

DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

74HC/HCT670 4 x 4 register file; 3-state

Product specification
File under Integrated Circuits, IC06

December 1990

4 x 4 register file; 3-state

74HC/HCT670

FEATURES

- Simultaneous and independent read and write operations
- Expandable to almost any word size and bit length
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT670 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT670 are 16-bit 3-state register files organized as 4 words of 4 bits each. Separated read and write address inputs (R_A, R_B and W_A, W_B) and enable inputs (R_E and W_E) are available, permitting simultaneous writing into one word location and reading from another location. The 4-bit word to be stored is presented to four data inputs (D₀ to D₃). The W_A and W_B inputs determine

the location of the stored word. When the $\overline{W_E}$ input is LOW, the data is entered into the addressed location. The addressed location remains transparent to the data while the $\overline{W_E}$ input is LOW. Data supplied at the inputs will be read out in true (non-inverting) form from the 3-state outputs (Q₀ to Q₃). D_n and W_n inputs are inhibited when $\overline{W_E}$ is HIGH.

Direct acquisition of data stored in any of the four registers is made possible by individual read address inputs (R_A and R_B). The addressed word appears at the four outputs when the $\overline{R_E}$ is LOW. Data outputs are in the high impedance OFF-state when $\overline{R_E}$ is HIGH. This permits outputs to be tied together to increase the word capacity to very large numbers.

Design of the read enable signals for the stacked devices must ensure that there is no overlap in the LOW levels which would cause more than one output to be active at the same time. Parallel expansion to generate n-bit words is accomplished by driving the enable and address inputs of each device in parallel.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | | UNIT |
|-------------------------------------|--|---|---------|-----|------|
| | | | HC | HCT | |
| t _{PHL} / t _{PLH} | propagation delay D _n to Q _n | C _L = 15 pF; V _{CC} = 5 V | 23 | 23 | ns |
| C _I | input capacitance | | 3.5 | 3.5 | pF |
| C _{PD} | power dissipation capacitance per package | notes 1 and 2 | 122 | 124 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \quad \text{where:}$$

f_i = input frequency in MHz
 f_o = output frequency in MHz
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs
 C_L = output load capacitance in pF
 V_{CC} = supply voltage in V

2. For HC the condition is V_I = GND to V_{CC};
 for HCT the condition is V_I = GND to V_{CC} - 1.5 V

ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

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PIN DESCRIPTION

| PIN NO. | SYMBOL | NAME AND FUNCTION |
|-------------|----------------------------------|---|
| 5, 4 | R _A , R _B | read address inputs |
| 8 | GND | ground (0 V) |
| 10, 9, 7, 6 | Q ₀ to Q ₃ | data outputs |
| 11 | \overline{RE} | 3-state output read enable input (active LOW) |
| 12 | \overline{WE} | write enable input (active LOW) |
| 14, 13 | W _A , W _B | write address inputs |
| 15, 1, 2, 3 | D ₀ to D ₃ | data inputs |
| 16 | V _{CC} | positive supply voltage |

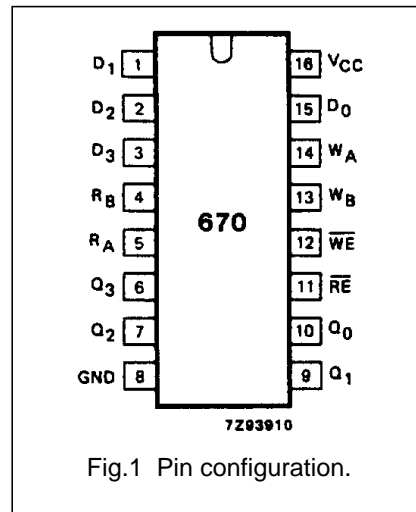


Fig.1 Pin configuration.

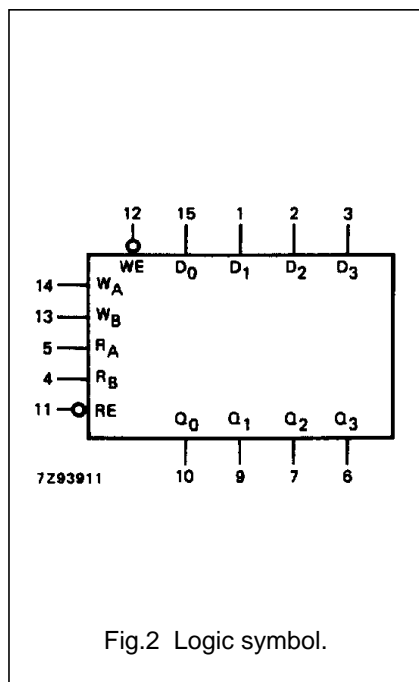


Fig.2 Logic symbol.

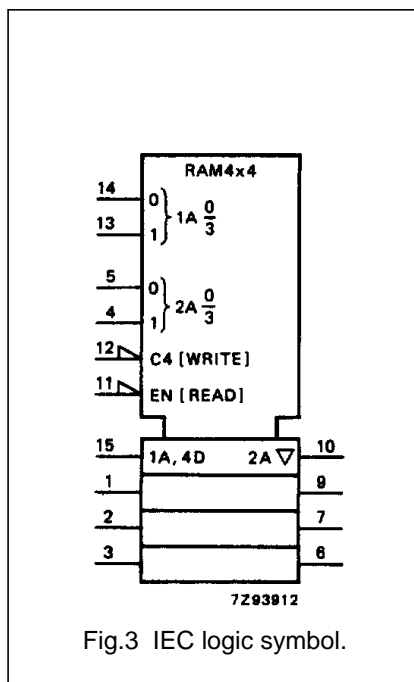


Fig.3 IEC logic symbol.

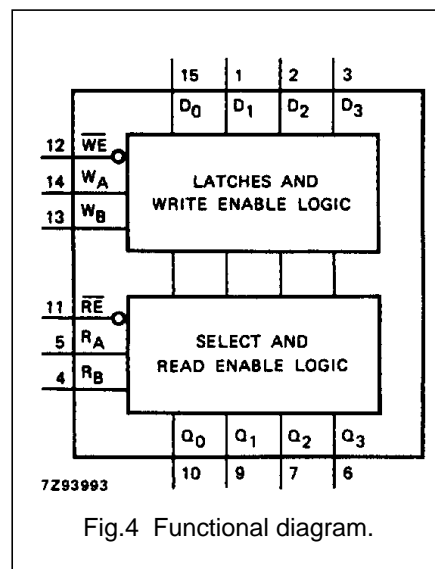


Fig.4 Functional diagram.

WRITE MODE SELECT TABLE

| OPERATING MODE | INPUTS | | INTERNAL LATCHES ⁽¹⁾ |
|----------------|-----------------|----------------|---------------------------------|
| | \overline{WE} | D _n | |
| write data | L | L | L |
| | L | H | H |
| data latched | H | X | no change |

Note

- The write address (W_A and W_B) to the "internal latches" must be stable while \overline{WE} is LOW for conventional operation.

READ MODE SELECT TABLE

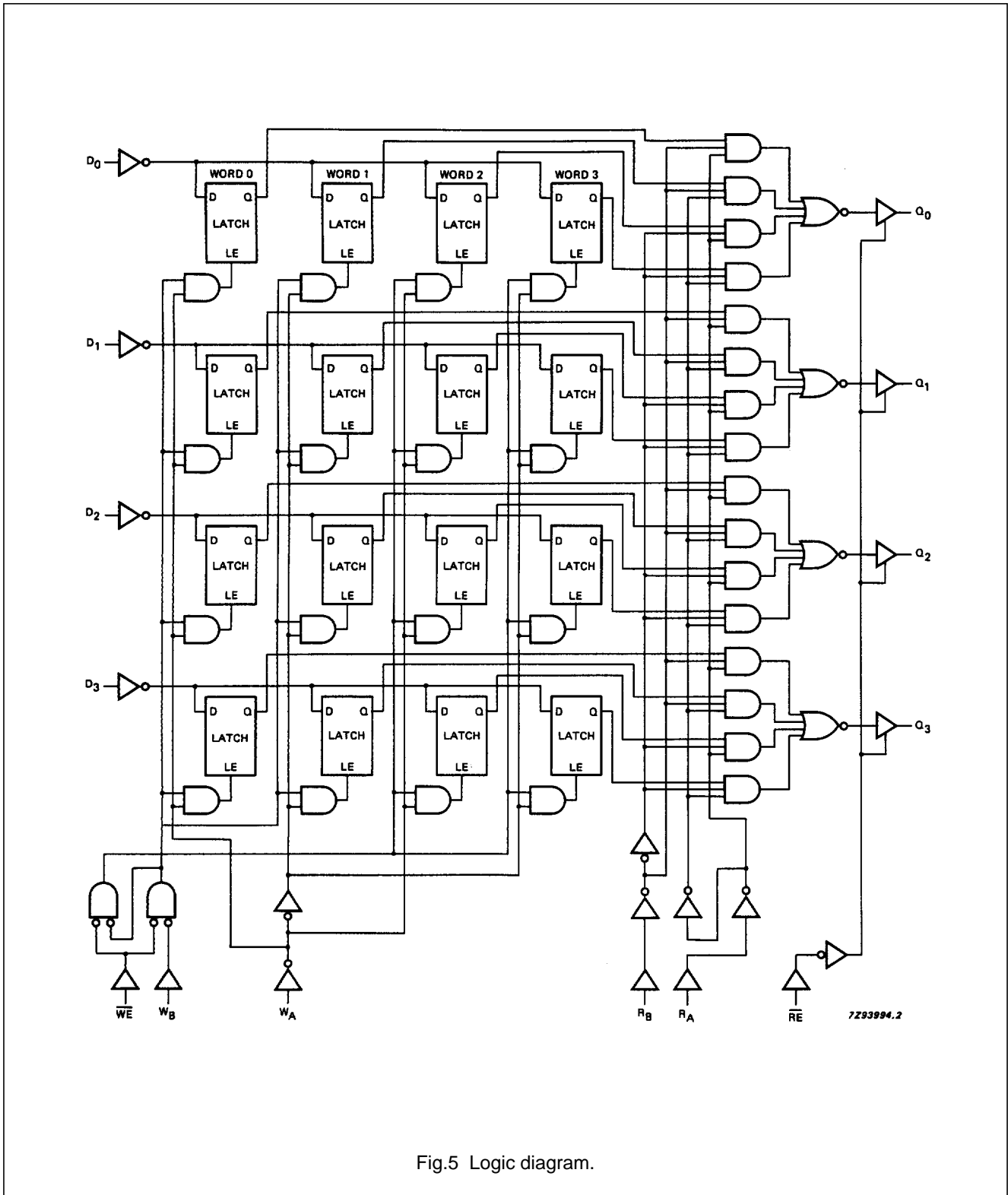
| OPERATING MODE | INPUTS | | OUTPUT |
|----------------|-----------------|---------------------------------|--------|
| | \overline{RE} | INTERNAL LATCHES ⁽¹⁾ | |
| read | L | L | L |
| | L | H | H |
| disabled | H | X | Z |

Notes

- The selection of the "internal latches" by read address (R_A and R_B) are not constrained by \overline{WE} or \overline{RE} operation.
 H = HIGH voltage level
 L = LOW voltage level
 X = don't care
 Z = high impedance OFF-state

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DC CHARACTERISTICS FOR 74HC

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*.

Output capability: bus driver

I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

| SYMBOL | PARAMETER | T _{amb} (°C) | | | | | | UNIT | TEST CONDITIONS | | |
|-------------------------------------|--|-----------------------|----------------|-----------------|-----------------|-----------------|-----------------|-----------------|------------------------|-------------------|-------|
| | | 74HC | | | | | | | V _{CC} (V) | WAVEFORMS | |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | |
| | | min. | typ. | max. | min. | max. | min. | | | | max. |
| t _{PHL} / t _{PLH} | propagation delay R _A , R _B to Q _n | | 58 21 17 | 195 39 33 | | 245 49 42 | | 295 59 50 | ns | 2.0 4.5 6.0 | Fig.6 |
| t _{PHL} / t _{PLH} | propagation delay \overline{WE} to Q _n | | 77 28 22 | 250 50 43 | | 315 63 54 | | 375 75 64 | ns | 2.0 4.5 6.0 | Fig.7 |
| t _{PHL} / t _{PLH} | propagation delay D _n to Q _n | | 74 27 22 | 250 50 43 | | 315 63 54 | | 375 75 64 | ns | 2.0 4.5 6.0 | Fig.7 |
| t _{PZH} / t _{PZL} | 3-state output enable time \overline{RE} to Q _n | | 39 14 11 | 150 30 26 | | 190 38 33 | | 225 45 38 | ns | 2.0 4.5 6.0 | Fig.9 |
| t _{PHZ} / t _{PLZ} | 3-state output disable time \overline{RE} to Q _n | | 47 17 14 | 150 30 26 | | 190 38 33 | | 225 45 38 | ns | 2.0 4.5 6.0 | Fig.9 |
| t _{THL} / t _{TLH} | output transition time | | 14 5 4 | 60 12 10 | | 75 15 13 | | 90 18 15 | ns | 2.0 4.5 6.0 | Fig.6 |
| t _W | write enable pulse width LOW | 80 16 14 | 14 5 4 | | 100 20 17 | | 120 24 20 | | ns | 2.0 4.5 6.0 | Fig.8 |
| t _{su} | set-up time D _n to \overline{WE} | 60 12 10 | 3 1 1 | | 75 15 13 | | 90 18 15 | | ns | 2.0 4.5 6.0 | Fig.8 |
| t _{su} | set-up time W _A , W _B to \overline{WE} | 60 12 10 | 6 2 2 | | 75 15 13 | | 90 18 15 | | ns | 2.0 4.5 6.0 | Fig.8 |
| t _h | hold time D _n to \overline{WE} | 5 5 5 | 0 0 0 | | 5 5 5 | | 5 5 5 | | ns | 2.0 4.5 6.0 | Fig.8 |
| t _h | hold time W _A , W _B to \overline{WE} | 5 5 5 | 0 0 0 | | 5 5 5 | | 5 5 5 | | ns | 2.0 4.5 6.0 | Fig.8 |
| t _{latch} | latch time \overline{WE} to R _A , R _B | 100 20 17 | 28 10 8 | | 125 25 21 | | 150 30 26 | | ns | 2.0 4.5 6.0 | Fig.8 |

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DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*.

Output capability: bus driver

I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

| INPUT | UNIT LOAD COEFFICIENT |
|----------------------------------|-----------------------|
| D _n | 0.25 |
| \overline{WE} , W _A | 0.40 |
| W _B | 0.60 |
| R _A | 0.70 |
| R _B | 1.10 |
| \overline{RE} | 1.35 |

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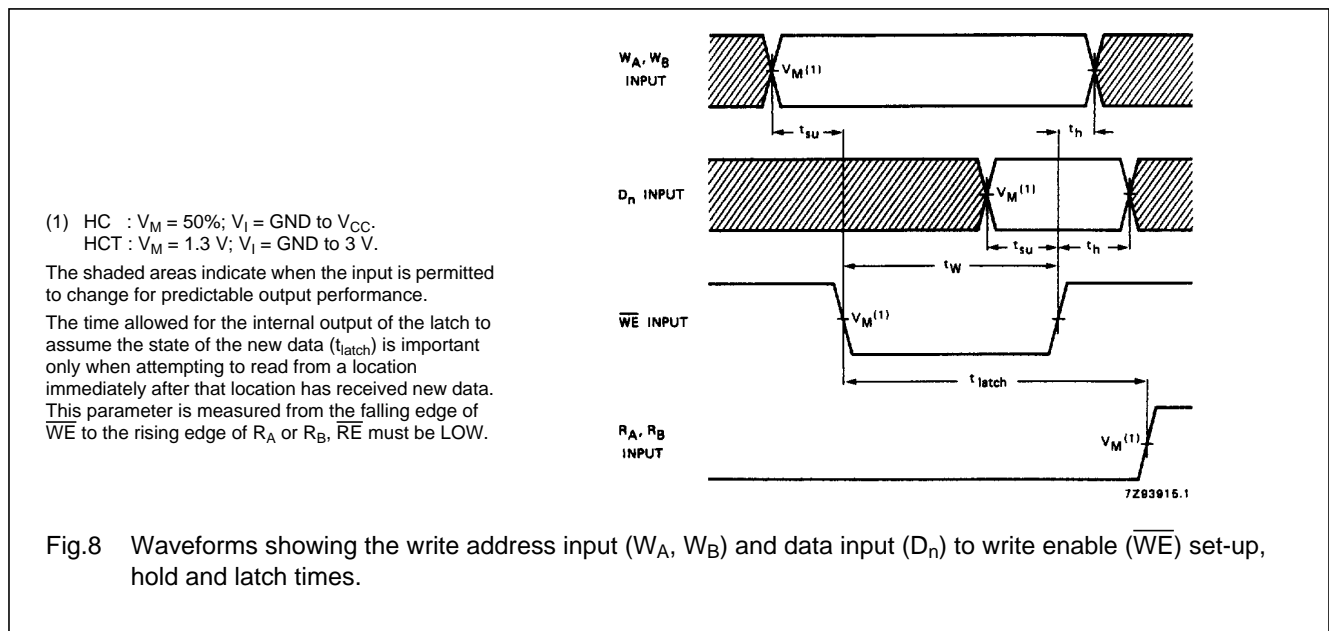
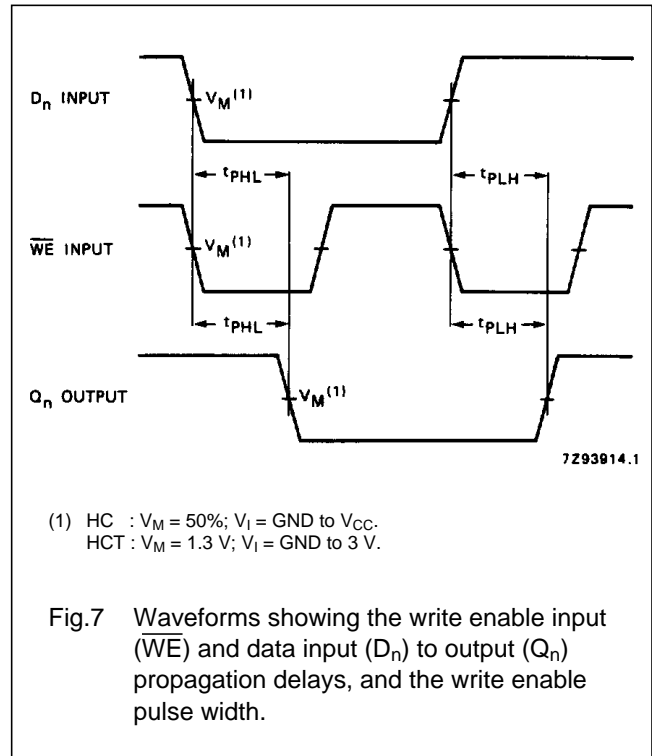
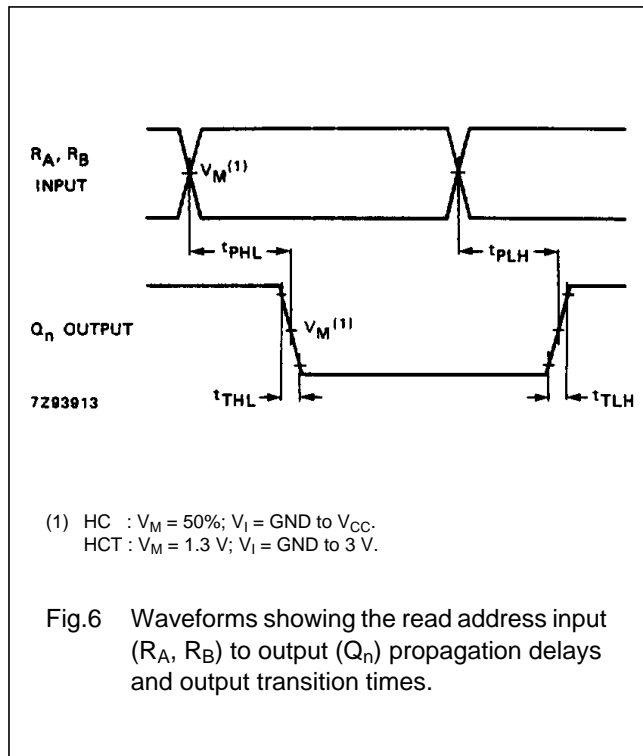
AC CHARACTERISTICS FOR 74HCTGND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

| SYMBOL | PARAMETER | T _{amb} (°C) | | | | | | | | UNIT | TEST CONDITIONS | |
|-------------------------------------|--|-----------------------|------|------|------------|------|-------------|------|----|------|------------------------|-----------|
| | | 74HCT | | | | | | | | | V _{CC} (V) | WAVEFORMS |
| | | +25 | | | -40 to +85 | | -40 to +125 | | | | | |
| | | min. | typ. | max. | min. | max. | min. | max. | | | | |
| t _{PHL} / t _{PLH} | propagation delay R _A , R _B to Q _n | | 21 | 40 | | 50 | | 60 | ns | 4.5 | Fig.6 | |
| t _{PHL} / t _{PLH} | propagation delay \overline{WE} to Q _n | | 28 | 50 | | 63 | | 75 | ns | 4.5 | Fig.7 | |
| t _{PHL} / t _{PLH} | propagation delay D _n to Q _n | | 27 | 50 | | 63 | | 75 | ns | 4.5 | Fig.7 | |
| t _{PZH} / t _{PZL} | 3-state output enable time RE to Q _n | | 18 | 35 | | 44 | | 53 | ns | 4.5 | Fig.9 | |
| t _{PHZ} / t _{PLZ} | 3-state output disable time \overline{RE} to Q _n | | 19 | 35 | | 44 | | 53 | ns | 4.5 | Fig.9 | |
| t _{THL} / t _{TLH} | output transition time | | 5 | 12 | | 15 | | 18 | ns | 4.5 | Fig.6 | |
| t _W | write enable pulse width LOW | 18 | 9 | | 23 | | 27 | | ns | 4.5 | Fig.8 | |
| t _{su} | set-up time D _n to \overline{WE} | 12 | 4 | | 15 | | 18 | | ns | 4.5 | Fig.8 | |
| t _{su} | set-up time W _A , W _B to \overline{WE} | 12 | -2 | | 15 | | 18 | | ns | 4.5 | Fig.8 | |
| t _h | hold time D _n to \overline{WE} | 5 | -1 | | 5 | | 5 | | ns | 4.5 | Fig.8 | |
| t _h | hold time W _A , W _B to \overline{WE} | 5 | 0 | | 5 | | 5 | | ns | 4.5 | Fig.8 | |
| t _{latch} | latch time \overline{WE} to R _A , R _B | 25 | 11 | | 31 | | 38 | | ns | 4.5 | Fig.8 | |

4 x 4 register file; 3-state

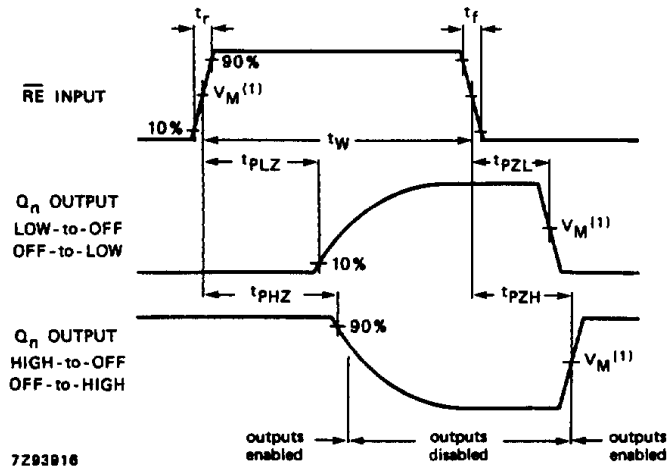
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AC WAVEFORMS



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(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
 HCT : $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.

Fig.9 Waveforms showing the read enable (\overline{RE}) to output (Q_n) enable and disable times, and the read enable pulse width.

PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".